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Kind regards,

Team Nexperia

## **DISCRETE SEMICONDUCTORS**

# DATA SHEET

# **PDTC143T series** NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = open

Product data sheet Supersedes data of 2004 Apr 06 2004 Aug 06



## NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = open

## PDTC143T series

#### **FEATURES**

- Built-in bias resistors
- · Simplified circuit design
- Reduction of component count
- · Reduced pick and place costs.

#### **APPLICATIONS**

- General purpose switching and amplification
- · Inverter and interface circuits
- · Circuit applications.

#### QUICK REFERENCE DATA

SYMBOL	PARAMETER	TYP.	MAX.	UNIT
$V_{CEO}$	collector-emitter voltage	_	50	V
Io	output current (DC)	_	100	mA
R1	bias resistor	4.7	_	kΩ
R2	open	_	_	-

#### **DESCRIPTION**

NPN resistor-equipped transistor (see "Simplified outline, symbol and pinning" for package details).

#### PRODUCT OVERVIEW

TVDE NUMBER	PACE	KAGE	MADIZING CODE	DND COMPLEMENT
TYPE NUMBER	PHILIPS	EIAJ	MARKING CODE	PNP COMPLEMENT
PDTC143TE	SOT416	SC-75	40	PDTA143TE
PDTC143TEF	SOT490	SC-89	11	PDTA143TEF
PDTC143TK	SOT346	SC-59	52	PDTA143TK
PDTC143TM	SOT883	SC-101	DM	PDTA143TM
PDTC143TS	SOT54 (TO-92)	SC-43	TC143T	PDTA143TS
PDTC143TT	SOT23	_	*33 <sup>(1)</sup>	PDTA143TT
PDTC143TU	SOT323	SC-70	*52 <sup>(1)</sup>	PDTA143TU

### Note

2004 Aug 06 2

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<sup>1. \* =</sup> p: Made in Hong Kong.

<sup>\* =</sup> t: Made in Malaysia.

<sup>\* =</sup> W: Made in China.

# NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = open

## PDTC143T series

## SIMPLIFIED OUTLINE, SYMBOL AND PINNING

TYPE NUMBER	CIMPLIFIED OUTLINE AND CYMPOL		PINNING
TYPE NUMBER	SIMPLIFIED OUTLINE AND SYMBOL	PIN	DESCRIPTION
PDTC143TS	1 R1 R1 3 MAM361	1 2 3	base collector emitter
PDTC143TE PDTC143TEF PDTC143TK PDTC143TT PDTC143TU	3 1 R1 2 Top view MDB270	1 2 3	base emitter collector
PDTC143TM	2 R1 3 Bottom view  MHCS07	1 2 3	base emitter collector

## NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = open

## PDTC143T series

#### **ORDERING INFORMATION**

TYPE NUMBER	PACKAGE						
ITPE NUMBER	NAME	ME DESCRIPTION					
PDTC143TE	_	plastic surface mounted package; 3 leads	SOT416				
PDTC143TEF	_	plastic surface mounted package; 3 leads	SOT490				
PDTC143TK	_	plastic surface mounted package; 3 leads	SOT346				
PDTC143TM	_	leadless ultra small plastic package; 3 solder lands; body $1.0 \times 0.6 \times 0.5$ mm	SOT883				
PDTC143TS	_	plastic single-ended leaded (through hole) package; 3 leads	SOT54				
PDTC143TT	-	plastic surface mounted package; 3 leads	SOT23				
PDTC143TU	_	plastic surface mounted package; 3 leads	SOT323				

### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	_	50	V
V <sub>CEO</sub>	collector-emitter voltage	open base	_	50	V
V <sub>EBO</sub>	emitter-base voltage	open collector	_	5	V
Io	output current (DC)		_	100	mA
I <sub>CM</sub>	collector current		_	100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C			
	SOT54	note 1	_	500	mW
	SOT23	note 1	_	250	mW
	SOT346	note 1	_	250	mW
	SOT323	note 1	_	200	mW
	SOT490	notes 1 and 2	_	250	mW
	SOT883	notes 2 and 3	_	250	mW
	SOT416	note 1	_	150	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C

#### **Notes**

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60  $\mu m$  copper strip line.

## NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = open

## PDTC143T series

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air		
	SOT54	note 1	250	K/W
	SOT23	note 1	500	K/W
	SOT346	note 1	500	K/W
	SOT323	note 1	625	K/W
	SOT490	notes 1 and 2	500	K/W
	SOT883	notes 2 and 3	500	K/W
	SOT416	note 1	833	K/W

#### **Notes**

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60  $\mu m$  copper strip line.

### **CHARACTERISTICS**

 $T_{amb}$  = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>CBO</sub>	collector-base cut-off current	V <sub>CB</sub> = 50 V; I <sub>E</sub> = 0 A	_	_	100	nA
I <sub>CEO</sub>	collector-emitter cut-off current	$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A}$	_	_	1	μΑ
		$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A}; T_{j} = 150 ^{\circ}\text{C}$	_	_	50	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = 5 V; I <sub>C</sub> = 0 A	_	_	100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 1 mA	200	_	_	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = 5 \text{ mA}; I_B = 0.25 \text{ mA}$	_	_	100	mV
R1	input resistor		3.3	4.7	6.1	kΩ
C <sub>c</sub>	collector capacitance	$I_E = i_e = 0 \text{ A}; V_{CB} = 10 \text{ V};$ f = 1 MHz	_	_	2.5	pF

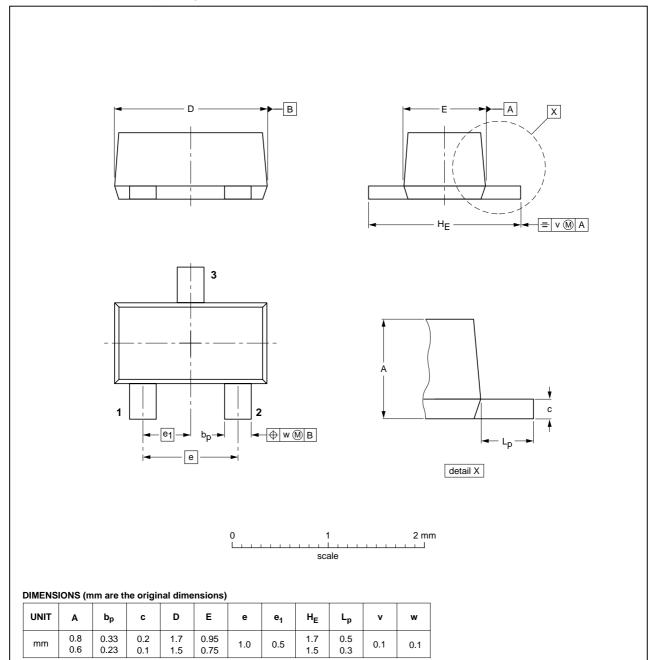
# NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = open

## PDTC143T series

#### **PACKAGE OUTLINES**

## Plastic surface-mounted package; 3 leads

SOT490

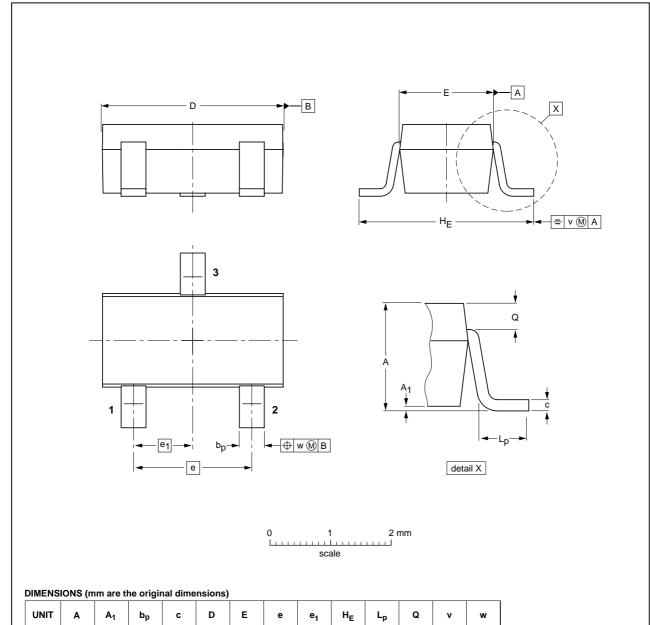


RE		REFERENCES		EUROPEAN	ISSUE DATE
IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
		SC-89			<del>05-07-28</del> 06-03-16
	IEC		IEC JEDEC JEITA	IEC JEDEC JEITA	IEC JEDEC JEITA PROJECTION

## PDTC143T series

## Plastic surface-mounted package; 3 leads

SOT346



OUTLINE	REFERE		REFERENCES EUROPEAN		REFERENCES		ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT346		TO-236	SC-59A			<del>-04-11-11</del> 06-03-16	

1.9

0.6

0.33

0.2

2004 Aug 06 7

0.1

0.013

0.50

0.35

0.26

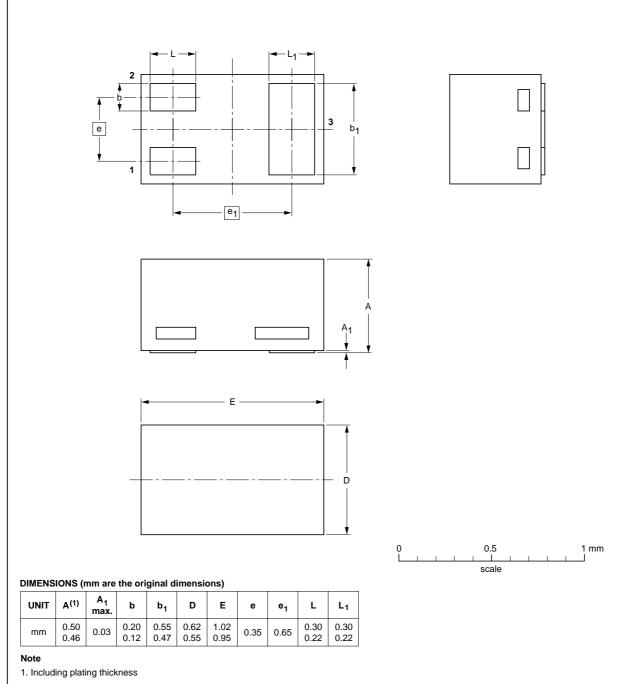
1.3

1.0

## PDTC143T series

## Leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.5 mm

**SOT883** 



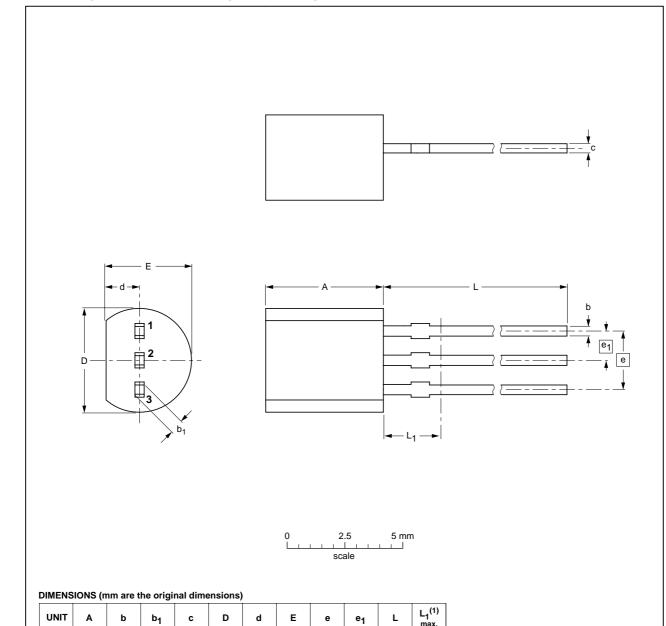
OUTLINE		REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT883			SC-101			<del>03-02-05</del> 03-04-03	

## NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = open

## PDTC143T series

## Plastic single-ended leaded (through hole) package; 3 leads

SOT54



# mm

0.48

0.40

5.0

0.66

0.55

0.45

0.38

4.8

4.4

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

1.7

1.4

4.2

3.6

2.54

OUTLINE		REFER	ENCES		EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEDEC JEITA PROJEC	PROJECTION	ISSUE DATE	
SOT54		TO-92	SC-43A			<del>04-06-28</del> 04-11-16

1.27

14.5

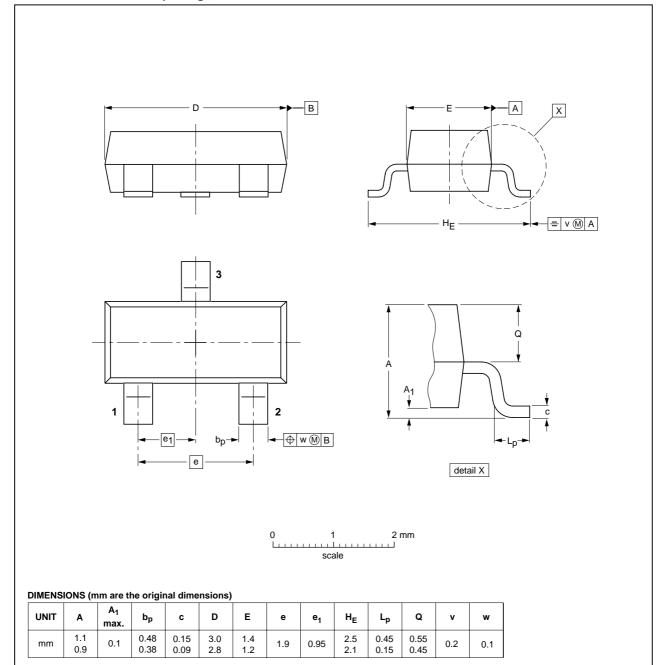
12.7

2.5

## PDTC143T series

## Plastic surface-mounted package; 3 leads

SOT23

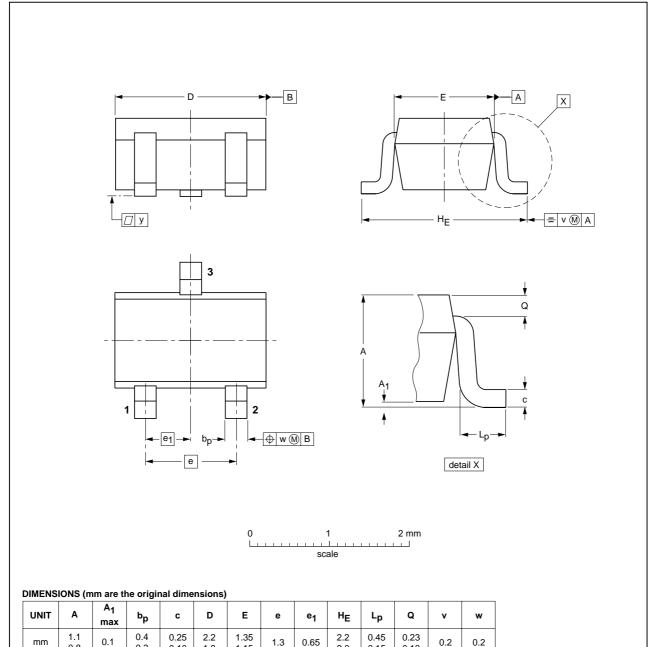


OUTLINE		REFERENCES EUROPEAN		ISSUE DATE		
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT23		TO-236AB			<del>-04-11-04</del> 06-03-16	

## PDTC143T series

## Plastic surface-mounted package; 3 leads

SOT323

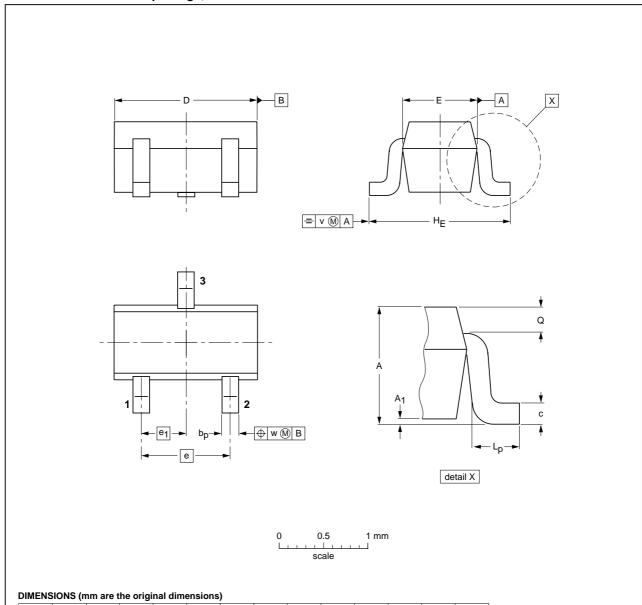


VERSION IEC JEDEC JEITA PROJECTION  SOT323  SC-70  O4-11-0	OUTLINE		REFER	EUROPEAN	ISSUE DATE		
SO(323)	VERSION	IEC	JEDEC	JEITA		PROJECTION	155UE DATE
06-03-	SOT323			SC-70			<del>04-11-04</del> 06-03-16

## PDTC143T series

## Plastic surface-mounted package; 3 leads

SOT416



U	NIT	Α	A <sub>1</sub> max	bp	С	D	E	е	e <sub>1</sub>	HE	Lp	ø	v	w
n	nm	0.95 0.60	0.1	0.30 0.15	0.25 0.10	1.8 1.4	0.9 0.7	1	0.5	1.75 1.45	0.45 0.15	0.23 0.13	0.2	0.2

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT416			SC-75			<del>04-11-04</del> 06-03-16

## NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = open

## PDTC143T series

#### **DATA SHEET STATUS**

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

#### **Notes**

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## **NXP Semiconductors**

#### **Customer notification**

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

#### **Contact information**

For additional information please visit: http://www.nxp.com
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